**Preferred Devices** 

# High Voltage Switching Diode

Device Marking:

- BAS19LT1 = JP
- BAS20LT1 = JR
- BAS21LT1 = JS
- BAS21DW5T1 = JS

#### **Features**

• Pb-Free Packages are Available

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Continuous Reverse Voltage  BAS19 BAS20 BAS21	V <sub>R</sub>	120 200 250	Vdc
Repetitive Peak Reverse Voltage  BAS19  BAS20  BAS21	V <sub>RRM</sub>	120 200 250	Vdc
Continuous Forward Current	IF	200	mAdc
Peak Forward Surge Current	I <sub>FM(surge)</sub>	625	mAdc
Maximum Junction Temperature	T <sub>Jmax</sub>	150	°C
Power Dissipation (Note 4)	$P_{D}$	385	mW

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

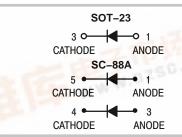
1. Mounted on FR-5 Board = 1.0 x 0.75 x 0.062 in.



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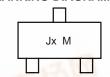
# HIGH VOLTAGE SWITCHING DIODE



#### **MARKING DIAGRAMS**



SOT-23 (TO-236) CASE 318 STYLE 8



Jx = Specific Device Code x = P, R or S M = Date Code



SC-88A (SOT-353) CASE 419A



XX = Specific Device Code

d = Date Code

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

**Preferred** devices are recommended choices for future use and best overall value.



#### THERMAL CHARACTERISTICS (SOT-23)

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board (Note 2)  T <sub>A</sub> = 25°C	P <sub>D</sub>	225	mW
Derate above 25°C		1.8	mW/°C
Thermal Resistance Junction-to-Ambient (SOT-23)	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate (Note 3)	P <sub>D</sub>	300	mW
T <sub>A</sub> = 25°C Derate above 25°C		2.4	mW/°C
Thermal Resistance Junction-to-Ambient	$R_{ heta JA}$	417	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C

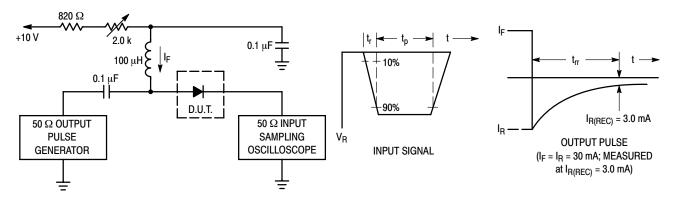
#### THERMAL CHARACTERISTICS (SC-88A)

Characteristic	Symbol	Max	Unit
Power Dissipation (Note 4)	$P_{D}$	385	mW
Thermal Resistance – Junction–to–Ambient Derate Above 25°C	$R_{ heta JA}$	328 3.0	°C/W mW/°C
Maximum Junction Temperature	T <sub>Jmax</sub>	150	°C
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

- 2. FR-5 =  $1.0 \times 0.75 \times 0.062$  in. 3. Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina. 4. Mounted on FR-5 Board =  $1.0 \times 0.75 \times 0.062$  in.

#### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
Reverse Voltage Leakage Current	I <sub>R</sub>			μAdc
(V <sub>R</sub> = 100 Vdc) BAS1	)	_	0.1	
$(V_R = 150 \text{ Vdc})$ BAS2	)	_	0.1	
$(V_R = 200 \text{ Vdc})$ BAS2		_	0.1	
$(V_R = 100 \text{ Vdc}, T_J = 150^{\circ}\text{C})$ BAS1	)	_	100	
$(V_R = 150 \text{ Vdc}, T_J = 150^{\circ}\text{C})$ BAS2	)	-	100	
$(V_R = 200 \text{ Vdc}, T_J = 150^{\circ}\text{C})$ BAS2		-	100	
Reverse Breakdown Voltage	V <sub>(BR)</sub>			Vdc
$(I_{BR} = 100 \mu\text{Adc})$ BAS1	)	120	_	
$(I_{BR} = 100 \mu\text{Adc})$ BAS2	)	200	_	
$(I_{BR} = 100 \mu\text{Adc})$ BAS2		250	-	
Forward Voltage	V <sub>F</sub>			Vdc
(I <sub>F</sub> = 100 mAdc)		_	1.0	
(I <sub>F</sub> = 200 mAdc)		_	1.25	
Diode Capacitance (V <sub>R</sub> = 0, f = 1.0 MHz)	C <sub>D</sub>	-	5.0	pF
Reverse Recovery Time ( $I_F = I_R = 30 \text{ mAdc}$ , $I_{R(REC)} = 3.0 \text{ mAdc}$ , $R_L = 100$ )	t <sub>rr</sub>	_	50	ns



Notes: 1. A 2.0 k $\Omega$  variable resistor adjusted for a Forward Current (I<sub>F</sub>) of 30 mA.

- 2. Input pulse is adjusted so  $I_{R(peak)}$  is equal to 30 mA.
- 3. t<sub>p</sub> » t<sub>rr</sub>

Figure 1. Recovery Time Equivalent Test Circuit

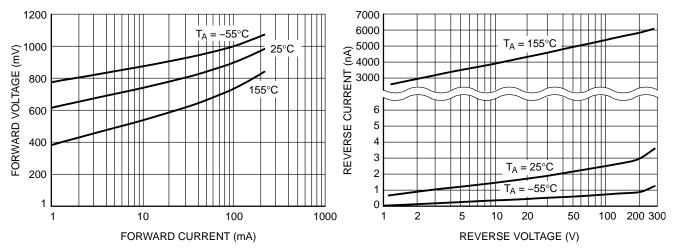


Figure 2. Forward Voltage

Figure 3. Reverse Leakage

#### **ORDERING INFORMATION**

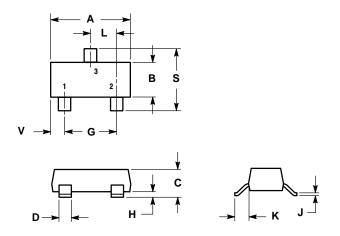
Device	Package	Shipping <sup>†</sup>	
BAS19LT1	SOT-23	2000 T /D	
BAS19LT1G	SOT-23 (Pb-Free)	3000 Tape/Reel	
BAS19LT3	SOT-23		
BAS19LT3G	SOT-23 (Pb-Free)	10000 Tape/Reel	
BAS20LT1	SOT-23		
BAS20LT1G	SOT-23 (Pb-Free)	3000 Tape/Reel	
BAS21LT1	SOT-23		
BAS21LT1G	SOT-23 (Pb-Free)	3000 Tape/Reel	
BAS21LT3	SOT-23		
BAS21LT3G	SOT-23 (Pb-Free)	10000 Tape/Reel	
BAS21DW5T1	SC-88A		
BAS21DW5T1G	SC-88A (Pb-Free)	3000 Tape/Reel	

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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#### **PACKAGE DIMENSIONS**

SOT-23 (TO-236) CASE 318-09 **ISSUE AH** 



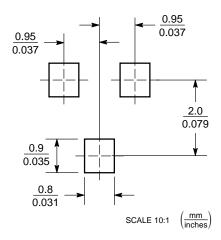
- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI
- DIMENSIONING AND TOLEHANCING PEH ANSI Y14.5M, 1982.
   CONTROLLING DIMENSION: INCH.
   MAXIUMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
   318-01, -02, AND -06 OBSOLETE, NEW STANDARD 318-09.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.1102	0.1197	2.80	3.04
В	0.0472	0.0551	1.20	1.40
C	0.0385	0.0498	0.99	1.26
D	0.0140	0.0200	0.36	0.50
G	0.0670	0.0826	1.70	2.10
Н	0.0040	0.0098	0.10	0.25
J	0.0034	0.0070	0.085	0.177
K	0.0180	0.0236	0.45	0.60
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.0984	2.10	2.50
٧	0.0177	0.0236	0.45	0.60

STYLE 8:
PIN 1. ANODE
2. NO CONNECTION

CATHODE

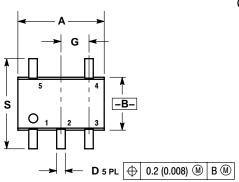
#### **SOLDERING FOOTPRINT\***

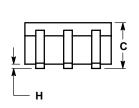


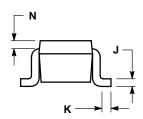
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

SC-88A (SOT-353) CASE 419A-02 ISSUE G





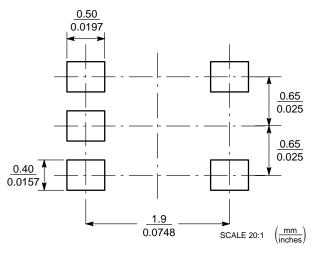


#### NOTES:

- DIMENSIONING AND TOLERANCING
   DEP ANGLY 14 FM 1993
- PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
- 3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE RUPPS

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65 BSC	
Н		0.004		0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20	REF
S	0.079	0.087	2.00	2.20

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb—Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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